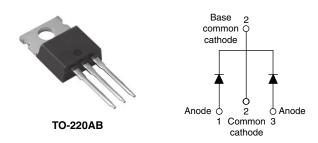
VS-MBR20...CTHN3 Series

Vishay Semiconductors

www.vishay.com

High Performance Schottky Rectifier, 2 x 10 A



PRODUCT SUMMARY									
I _{F(AV)}	2 x 10 A								
V _R	35 V, 45 V								
V _F at I _F	0.57 V								
I _{RM} max.	15 mA at 125 °C								
T _J max.	150 °C								
E _{AS}	8 mJ								
Package	TO-220AB								
Diode variation	Common cathode								

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- RoHS COMPLIANT HALOGEN FREE
- Guard ring for enhanced ruggedness and long term reliability
- AEC-Q101 qualified meets JESD 201 class 2 whisker test
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform (per device)	20	А						
V _{RRM}		35/45	V						
I _{FRM}	$T_{\rm C} = 135 \ ^{\circ}{\rm C}$ (per leg)	20	٨						
I _{FSM}	t _p = 5 μs sine	1060	A						
V _F	10 A _{pk} , T _J = 125 °C	0.57	V						
TJ	Range	-65 to 150	°C						

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-MBR2035CTHN3	VS-MBR2045CTHN3	UNITS				
Maximum DC reverse voltage	V _R	35	45	V				
Maximum working peak reverse voltage	V _{RWM}	35	45	v				

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST	VALUES	UNITS					
Maximum average per leg		$T = 125 ^{\circ}\text{C}$ roted V		10					
forward current per device	I _{F(AV)}	T_{C} = 135 °C, rated V_{R}		20					
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20	kHz, T _C = 135 °C	20					
Non-repetitive peak surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1060	А				
		Surge applied at rated load single phase, 60 Hz	150						
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to Frequency limited by T _J ma	2						
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 2 \text{ A}, L = 4$	mH	8	mJ				

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS						
		20 A	T _J = 25 °C	0.84					
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	T.I = 125 °C	0.57	V				
		20 A	IJ = 125 C	0.72					
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.1	mA				
Maximum instantaneous reverse current	IRM (")	T _J = 125 °C	haled DC vollage	15					
Threshold voltage	V _{F(TO)}	T T maximum		0.354	V				
Forward slope resistance	r _t	$T_J = T_J maximum$	17.6	mΩ					
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal ran	ge 100 kHz to 1 MHz) 25 °C	600	pF				
Typical series inductance	L _S	Measured from top of tern	8.0	nH					
Maximum voltage rate of change	dV/dt	Rated V _R	Rated V _R						

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction temper	ature range	TJ		-65 to 150	0°				
Maximum storage tempera	ature range	T _{Stg}		-65 to 175	U				
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	2.0	°C/W				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased (only for TO-220)	0.50	0/10				
Approximate weight				2	g				
Approximate weight				0.07	oz.				
Mounting torque	minimum		Non-lubricated threads	6 (5)	kgf ⋅ cm				
Mounting torque	maximum		Non-lubricated trireads	12 (10)	(lbf ⋅ in)				
Marking davias				MBR2035CTH					
Marking device			Case style TO-220AB	MBR2045CTH					



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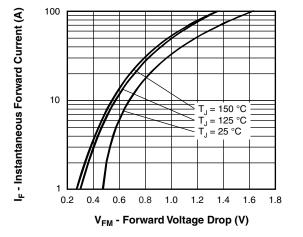


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

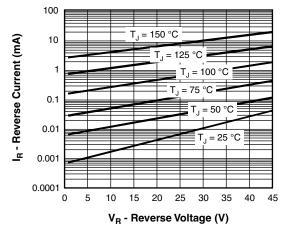


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

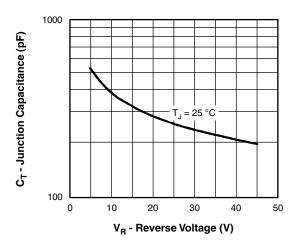


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

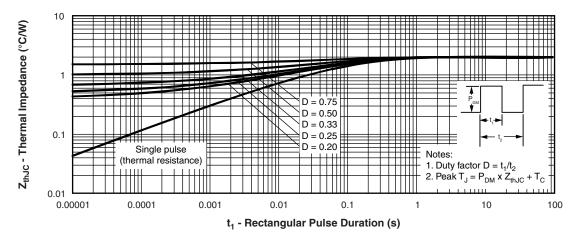


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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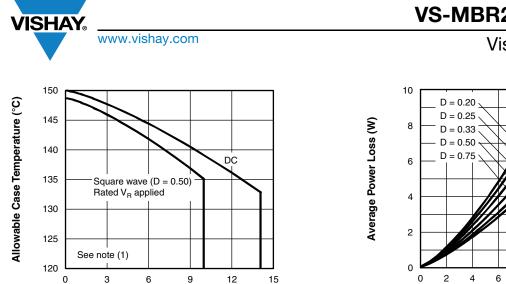


Fig. 5 - Maximum Allowable Case Temperature vs.



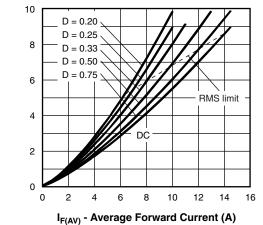


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

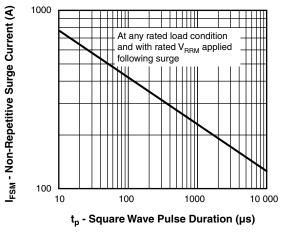


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{Rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ VS-MBR20...CTHN3 Series

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ORDERING INFORMATION TABLE

Device code	vs-	MBR	20	45	ст	Н	N3
(1	2	3	4	5	6	7
1 2 3 4 5 6 7		Sch Curr Volt CT H =	ottky MI rent ratii age rati = Essen AEC-Q	niconduo BR serie ng (20 = ngs — tial part 101 qua ntal digit	es 20 A) number ilified	35 45	= 35 V = 45 V

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-MBR2035CTHN3	50	1000	Antistatic plastic tube						
VS-MBR2045CTHN3	50	1000	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS							
Dimensions <u>www.vishay.com/doc?95222</u>							
Part marking information TO-220AB-N3	www.vishay.com/doc?95028						
SPICE model	www.vishay.com/doc?95295						

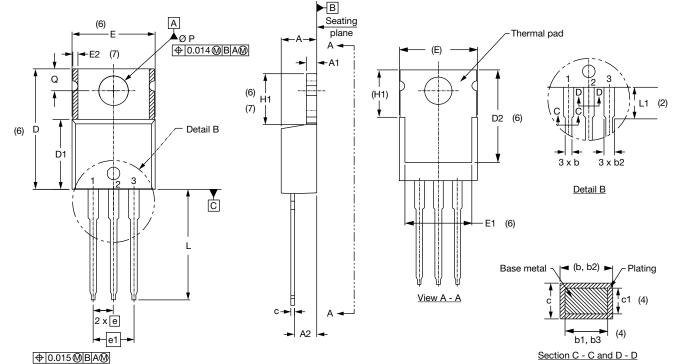
Outline Dimensions



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TO-220AB

DIMENSIONS in millimeters and inches



Lead tip

Conforms to JEDEC[®] outline TO-220AB

SYMBOL	MILLIMETERS		INC	HES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183		D2	11.68	12.88	0.460	0.507	6
A1	1.14	1.40	0.045	0.055		E	10.11	10.51	0.398	0.414	3, 6
A2	2.56	2.92	0.101	0.115		E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040		E2	-	0.76	-	0.030	7
b1	0.38	0.97	0.015	0.038	4	е	2.41	2.67	0.095	0.105	
b2	1.20	1.73	0.047	0.068		e1	4.88	5.28	0.192	0.208	
b3	1.14	1.73	0.045	0.068	4	H1	5.84	6.86	0.230	0.270	6, 7
С	0.36	0.61	0.014	0.024		L	13.52	14.02	0.532	0.552	
c1	0.36	0.56	0.014	0.022	4	L1	3.32	3.82	0.131	0.150	2
D	14.85	15.25	0.585	0.600	3	ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355		Q	2.60	3.00	0.102	0.118	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Dimension b1, b3 and c1 apply to base metal only

⁽⁵⁾ Controlling dimensions: inches

⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1

⁽⁷⁾ Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed

(8) Outline conforms to JEDEC[®] TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

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